

# 74V1T04

# SINGLE INVERTER

**PRELIMINARY DATA** 

- HIGH SPEED:  $t_{PD} = 4.7 \text{ ns}$  (TYP.) at  $V_{CC} = 5V$
- LOW POWER DISSIPATION:  $I_{CC} = 1 \mu A \text{ (MAX.)}$  at  $T_A = 25 \,^{\circ}\text{C}$
- COMPATIBLE WITH TTL OUTPUTS: V<sub>IH</sub> = 2V (MIN), V<sub>IL</sub> = 0.8V (MAX)
- POWER DOWN PROTECTION ON INPUT & OUTPUT
- SYMMETRICAL OUTPUT IMPEDANCE: |loH| = loL = 8 mA (MIN)
- BALANCED PROPAGATION DELAYS:
  tplh ≅ tphl
- OPERATING VOLTAGE RANGE:
   Vcc (OPR) = 4.5V to 5.5V
- IMPROVED LATCH-UP IMMUNITY

#### **DESCRIPTION**

The 74V1T04 is an advanced high-speed CMOS SINGLE INVERTER fabricated with sub-micron silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology. It has similar high speed performance of equivalent Bipolar Schottky TTL combined with true CMOS low power dissipation.

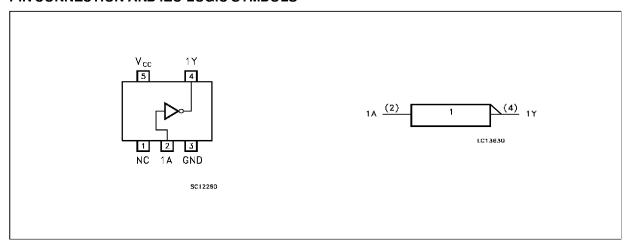


The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

Power down protection is provided on input and output and 0 to 7V can be accepted on input with no regard to the supply voltage. This device can be used to interface 5V to 3V.

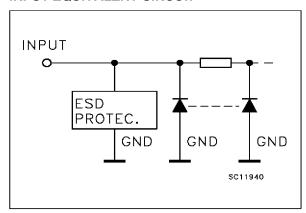
Input and output are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

#### PIN CONNECTION AND IEC LOGIC SYMBOLS



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# INPUT EQUIVALENT CIRCUIT



## **PIN DESCRIPTION**

PIN No	SYMBOL	NAME AND FUNCTION
1	N.C.	Not Connected
2	1A	Data Input
4	1Y	Data Output
3	GND	Ground (0V)
5	V <sub>CC</sub>	Positive Supply Voltage

#### **TRUTH TABLE**

Α	Υ
L	Н
Н	L

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
Vcc	Supply Voltage	-0.5 to +7.0	٧
Vı	DC Input Voltage	-0.5 to +7.0	V
Vo	DC Output Voltage (see note 1)	-0.5 to +7.0	V
Vo	DC Output Voltage (see note 2)	-0.5 to V <sub>CC</sub> + 0.5	٧
lıĸ	DC Input Diode Current	- 20	mA
lok	DC Output Diode Current	± 20	mA
lo	DC Output Current	± 25	mA
Icc or Igno	DC V <sub>CC</sub> or Ground Current	± 50	mA
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C
TL	Lead Temperature (10 sec)	260	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Value	Unit
Vcc	Supply Voltage	4.5 to 5.5	V
$V_{l}$	Input Voltage	0 to 5.5	V
Vo	Output Voltage (see note 1)	0 to 5.5	V
Vo	Output Voltage (see note 2)	0 to V <sub>CC</sub>	V
Top	Operating Temperature	-40 to +85	°C
dt/dv	Input Rise and Fall Time (see note 3) $(V_{CC} = 5.0 \pm 0.5V)$	0 to 20	ns/V

<sup>1)</sup> V<sub>CC</sub> = 0V

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 $<sup>1)\</sup> V_{CC}=0V$ 

<sup>2)</sup> High or Low State

<sup>2)</sup> High or Low State 3)V<sub>IN</sub> from 0.8V to 2 V

## **DC SPECIFICATIONS**

Symbol	Parameter	Tes	t Condi	itions			Value			Unit
		Vcc			T <sub>A</sub> = 25 °C		,C	-40 to 85 °C		
		(V)			Min.	Тур.	Max.	Min.	Max.	
V <sub>IH</sub>	High Level Input Voltage	4.5 to 5.5			2			2		V
VIL	Low Level Input Voltage	4.5 to 5.5					0.8		0.8	V
VoH	High Level Output	4.5	V   =	Ιο=-50 μΑ	4.4	4.5		4.4		V
	Voltage	4.5	VIL	lo=-8 mA	3.94			3.8		V
Vol	Low Level Output	4.5	V   =	Ιο=50 μΑ		0.0	0.1		0.1	V
	Voltage	4.5	VIH	I <sub>O</sub> =8 mA			0.36		0.44	V
I <sub>I</sub>	Input Leakage Current	0 to 5.5	V <sub>1</sub> = 5.	5V or GND			±0.1		±1.0	μΑ
lcc	Quiescent Supply Current	5.5	V <sub>I</sub> = V	<sub>CC</sub> or GND			1		10	μА
Δlcc	Additional Worst Case Supply Current	5.5	other in	put at 3.4V, put at V <sub>CC</sub> or GND			1.35		1.5	mA
IOPD	Output Leakage Current	0	Vol	ı⊤ = 5.5 <b>V</b>	0		0.5		5.0	μА

## AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3 \text{ ns}$ )

Symbol	Parameter	Test Condition		Value					Unit
		Vcc (*)		Т.	A = 25 °	C	-40 to	85 °C	
		(V)		Min.	Тур.	Max.	Min.	Max.	
t <sub>PLH</sub>	Propagation Delay	5.0	C <sub>L</sub> = 15 pF		4.7	6.7	1.0	7.5	20
t <sub>PHL</sub>	Time	5.0	C∟ = 50 pF		5.5	7.7	1.0	8.5	ns

<sup>(\*)</sup> Voltage range is 5V ± 0.5V

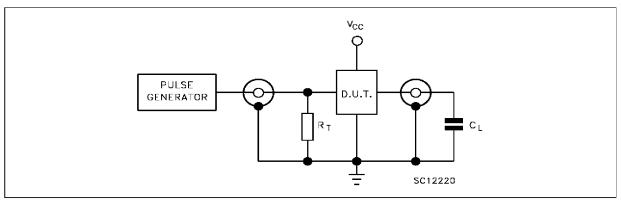
#### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Test Conditions	Value					Unit
			T <sub>A</sub> = 25 °C		-40 to 85 °C			
			Min.	Тур.	Max.	Min.	Max.	
C <sub>IN</sub>	Input Capacitance			4	10		10	рF
C <sub>PD</sub>	Power Dissipation Capacitance (note 1)			14				pF

<sup>1)</sup>  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation.  $I_{CC}(qpr) = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}$ 



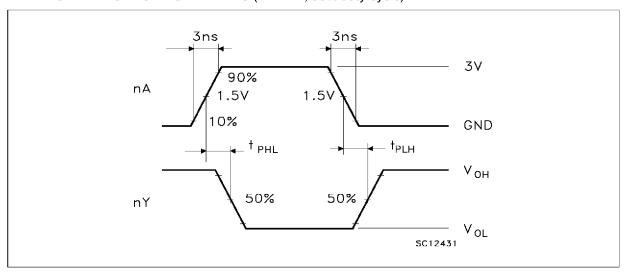
## **TEST CIRCUIT**



 $C_L = 15/50 \text{ pF}$  or equivalent (includes jig and probe capacitance)

 $R_T = Z_{OUT}$  of pulse generator (typically 50 $\Omega$ )

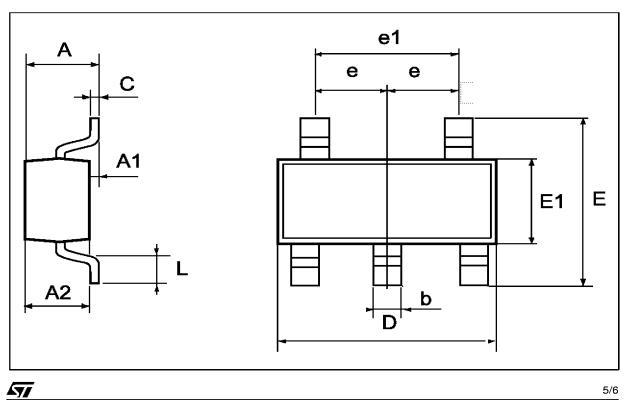
# WAVEFORM: PROPAGATION DELAYS (f=1MHz; 50% duty cycle)



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# **SOT23-5L MECHANICAL DATA**

DIM.	mm			mils				
<b></b>	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.		
А	0.90		1.45	35.4		57.1		
A1	0.00		0.15	0.0		5.9		
A2	0.90		1.30	35.4		51.2		
b	0.35		0.50	13.7		19.7		
С	0.09		0.20	3.5		7.8		
D	2.80		3.00	110.2		118.1		
E	2.60		3.00	102.3		118.1		
E1	1.50		1.75	59.0		68.8		
L	0.35		0.55	13.7		21.6		
е		0.95			37.4			
e1		1.9			74.8			



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